

Two-line TVS Diode

General Description

The AOZ8222DI-05 is a two-line transient voltage suppressor diode designed to protect voltage sensitive electronics from high transient conditions and ESD.

This device incorporates two TVS diodes in an ultra-small DFN 1.0 x 0.6 package. During transient conditions, the TVS diodes directs the transient to ground. The AOZ8222DI-05 may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (\pm 15 kV air, \pm 8 kV contact discharge).

The AOZ8222DI-05 comes in an RoHS compliant 3-lead DFN package and is rated over a -40 °C to +85 °C ambient temperature range.

The ultra-small 1.0 mm x 0.6 mm x 0.5 mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

Features

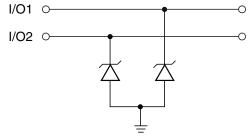
- ESD protection for high-speed data lines:
 - Exceeds IEC 61000-4-2 (ESD): ± 20 kV (air),
 ± 20 kV (contact)
 - Human Body Model (HBM) ± 30 kV
- Small package saves board space
- Low insertion loss
- Low clamping voltage
- Low operating voltage: 5 V

Applications

- Portable handheld devices
- Keypads, data lines, buttons
- Notebook computers
- Digital Cameras
- Portable GPS
- MP3 players

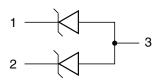


Typical Application



Unidirection Protection of Two Line

Pin Configuration





Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8222DI-05	-40 °C to +85 °C	DFN 1.0 x 0.6-3L	Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.

 $Please\ visit\ www.aosmd.com/media/AOSGreen Policy.pdf\ for\ additional\ information.$

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	AOZ8222DI-05DI-05			
Peak Pulse Current, t _P = 8/20 μs	5.5 A			
Peak Pulse Power, t _P = 8/20 μs	50 W			
Storage Temperature (T _S)	-65 °C to +150 °C			
ESD Rating per IEC61000-4-2, Contact ⁽¹⁾	± 20 kV			
ESD Rating per IEC61000-4-2, Air ⁽¹⁾	± 20 kV			
ESD Rating per Human Body Model ⁽²⁾	± 30 kV			

Notes:

- 1. IEC 61000-4-2 discharge with C_Discharge = 150 pF, R_Discharge = 330 $\Omega.$
- 2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge}$ = 100 pF, $R_{Discharge}$ = 1.5 k Ω .

Maximum Operating Ratings

Parameter	Rating
Junction Temperature (T _J)	-40 °C to +125 °C

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Electrical Characteristics

T_A = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit s
V _{RWM}	Reverse Working Voltage	Between I/O and VN ⁽³⁾			5.0	٧
V _{BR}	Reverse Breakdown Voltage	I _T = 1 mA, between I/O and VN ⁽⁴⁾	6.0			V
I _R	Reverse Leakage Current	V _{RWM} = 5 V, between I/O and VN			1	μA
V _F	Diode Forward Voltage	I _F = 10 mA	0.6	0.7	0.9	V
V _{CL}	Channel Clamp Voltage Positive Transients Negative Transients	I_{PP} = 1 A, tp = 100 ns, any I/O pin to Ground ⁽⁵⁾⁽⁶⁾			8.0 -2.0	V V
	Channel Clamp Voltage Positive Transients Negative Transients	I_{PP} = 5 A, tp = 100 ns, any I/O pin to Ground ⁽⁵⁾⁽⁶⁾			9.0 -5.0	V V
	Channel Clamp Voltage Positive Transients Negative Transients	I _{PP} = 12 A, tp = 100 ns, any I/O pin to Ground ⁽⁵⁾⁽⁶⁾			10.0 -10.0	V V
CJ	Channel Input Capacitance	V _R = 0 V, f = 1 MHz, between I/O pins ⁽⁶⁾		8	9	pF
		V _R = 0 V, f = 1 MHz, any I/O pin to Ground ⁽⁶⁾		15	18	pF

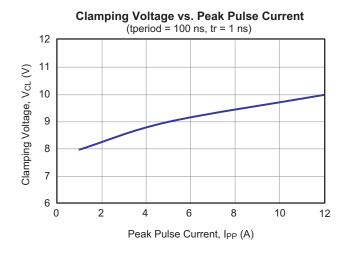
Notes:

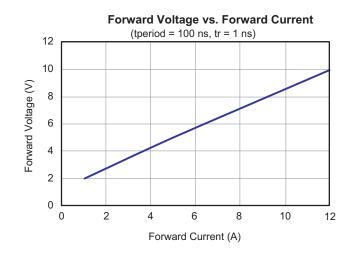
- 3. The working peak reverse voltage, VRWM, should be equal to or greater than the DC or continuous peak operating voltage level.
- 4. V_{BR} is measured at the pulse test current I_T .
- 5. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.
- 6. Guaranteed by design and characterization.

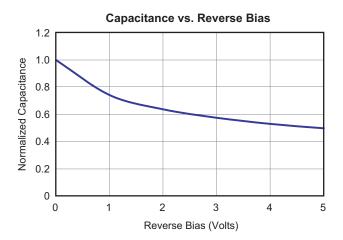
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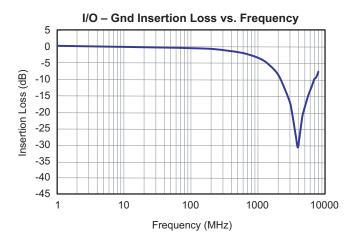


Typical Performance Characteristics





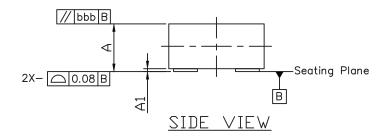


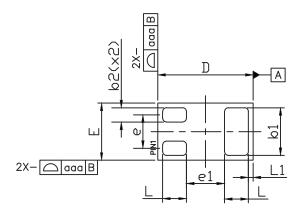


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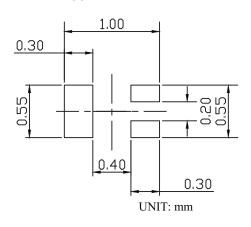
Package Dimensions, DFN1.0x0.6





BOTTOM VIEW

RECOMMENDED LAND PATTERN



SYMBOLS	DIMENS	IONS IN MIL	LIMETERS	DIMENSIONS IN INCHES				
SIMBULS	MIN	NDM	MAX	MIN	NDM	MAX		
Α	0.47	0.52	0.55	0.019	0.020	0.022		
A1	0.00	0.03	0.05	0.000	0.001	0.002		
b1	0.45	0.50	0.55	0.018	0.020	0.022		
b2	0.10	0.15	0.20	0.004	0.006	0.008		
D	0.95	1.00	1.05	0.037	0.039	0.041		
E	0.55	0.60	0.65	0.022	0.024	0.026		
e		0.35			0.014			
e1		0.40			0.016			
L	0.20	0.25	0.30	0.008	0.010	0.012		
L1		0.05		0.002				
۵۵۵		0.15		0.006				
bbb		0.05	0.002					

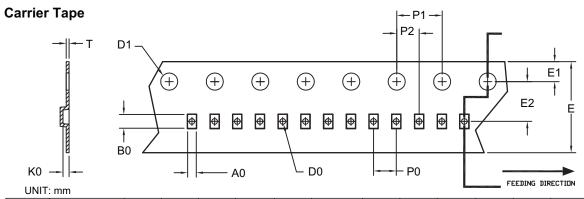
NOTE

- 1. ALL DIMENSION ARE IN MILLIMETERS.ANGLES ARE IN DEGREES.
- 2. COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.

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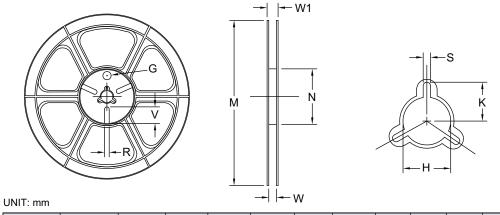


Tape and Reel Dimensions, DFN1.0x0.6



Option	Package	A0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
А	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.69 ±0.05	1.19 ±0.05	0.66 ±0.05	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.05	4.00 ±0.10	2.00 ±0.05	0.23 ±0.02
В	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.65 ±0.04	1.05 ±0.04	0.61 ±0.04	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.20 ±0.05

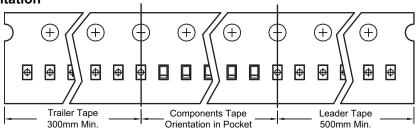




T	ape Size	Reel Size	M	N	W	W1	Н	K	S	G	R	V
	8mm	ø178	ø178 ±0.5	ø55 ±1	8.4 +1.5/-0	Max. 14.4	ø13.0 ±0.5	Max. 10.1	2.0 ±0.5	N/A	N/A	N/A

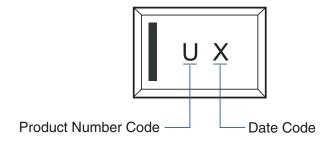
Leader / Trailer & Orientation







Part Marking



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